

Signal Integrity and TDR Analysis of Adjacent Microstrip Lines

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Introduction

The signal integrity (SI) analysis gives an overview of the quality of an electrical signal transmitted through electrical circuits such as high-speed interconnects, cables, and printed circuit boards. The quality of the received signal can be distorted by noise from outside the circuit, and can be degraded by impedance mismatch, insertion loss, and crosstalk; in practice, EMC/EMI analyses are run to estimate the susceptibility of a device or a network to an undesired coupling. In this example model, we examine the crosstalk effect between two adjacent microstrip lines on a microwave substrate. The simulated results provide the time-domain reflectometry (TDR) response at the coupled ports and show increased distortion of a signal at higher data rates.



Figure 1: A microstrip line crosstalk model is composed of 20 mil microwave substrate with a ground plane and two adjacent microstrip lines 1.8 mm apart.

Model Definition

Two parallel 50 Ω microstrip lines are patterned on 20 mil substrate with a dielectric constant $\varepsilon_r = 3.38$. All metallic parts, including the patterned lines and bottom ground plane, are configured using perfect electric conductor (PEC) boundary conditions. The small rectangular surfaces, bridging between two parallel lines and the ground plane, are used to model lumped ports with which the microstrip lines are excited or terminated by

50 Ω . The air domain on top of the circuit board is defined using vacuum material properties. The exterior surfaces of the air are finished by a scattering boundary condition that is an absorbing boundary to describe an open space.

One bit of a single rectangular pulse is used to excite the circuit board. The widths of the two pulses are set to half of the 300 MHz and 600 MHz signals. The corresponding data rates for each frequency are 600 Mbit/s and 1.2 Gbit/s, respectively. A parametric sweep switches the frequency of the pulse during the simulation. It is necessary to apply smoothing to the transition zone of the pulse to remove undesirable high-frequency components from the signal.

The maximum simulation time is calculated using an approximated traveling time of a wave through a microstrip line based on the phase velocity. The effective dielectric constant for the phase velocity calculation is obtained using an equation in Ref. 1

$$\frac{\varepsilon_r + 1}{2} + \frac{\varepsilon_r - 1}{2\sqrt{1 + 12\frac{d}{W}}} \tag{1}$$

where d is the thickness of the substrate and W is the width of the line.

It is assumed that a frequency about ten times greater than the input pulse signal frequency is enough to describe the highest frequency component in the smoothed rectangular pulse. The maximum mesh element size is set to 0.2 wavelengths in the dielectric substrate.

It is also important to define a time step that resolves the wave well in time as the mesh does in space. Any longer time steps would not optimally utilize the fine mesh, and any shorter time steps would unnecessarily lead to a longer simulation time without gaining significant accurate results. While running a simulation, the time step is continuously adjusted to meet the specified tolerances by the time-dependent solver. If there is an exact time step the solver needs to take, it can be manually set. In the Settings window of the Time-Dependent Solver node, the time step can be specified manually. See the step by step instructions to learn how to access this setting.

Results and Discussion

Figure 2 shows the input pulse signal as well as the voltage at lumped port 1 with a data rate of 600 Mbit/s (300 MHz) and 1.2 Gbit/s (600 MHz), respectively. Since the input signal is flowing through a straight 50 Ω line terminated with a 50 Ω resistor without discontinuity on the line, no distortion is evident on the port voltage.



Figure 2: The input pulse and the voltage at lumped port 1 (the excitation port) with a data rate of 600 Mbit/s and 1.2 Gbit/s.



Figure 3: The delayed input pulse and the voltage at lumped port 2 (the through port) with a data rate of 600 Mbit/s and 1.2 Gbit/s.



Figure 4: Voltage for the coupled signals at lumped ports 3 and 4. They are near-end crosstalk (NEXT) and far-end crosstalk (FEXT), respectively. The voltage of a coupled signal increases at a higher data rate.



Figure 5: The spectrum of input pulses up to 10 GHz. The signal strength decreases as frequency increases.



Figure 6: The impedance of lumped port 1 with data rates of 600 Mbit/s and 1.2 Gbit/s

Figure 3 shows the delayed input pulse and the received signals with two data rates at lumped port 2. The time domain response of the 1.2 Gbit/s signal is slightly distorted in the beginning when it reaches 1 V while that of the 600 Mbit/s signal seems to remain undistorted.

The crosstalk between two microstrip lines is observed in Figure 4. The coupled signal, near-end crosstalk (NEXT), level between two data rates is quite similar at lumped port 3, which is next to the excitation port. The time domain response at lumped port 4 next to the through port, far-end crosstalk (FEXT), shows that the higher data rate signal causes the stronger crosstalk on another signal path.

Figure 5 works as a reference to define the effective highest frequency component in the smoothed rectangular pulse since it provides the spectrum of results for 600 Mbit/s and 1.2 Gbit/s. A periodic rectangular pulse can be decomposed into a sum of sinusoidal functions. By estimating the level of a particular frequency, a proper frequency range can be defined for efficient simulations. The estimated highest frequency is used to choose the mesh size. With a finer mesh size, higher frequency components can be analyzed more accurately but it will increase the computation time. In this model, we set the maximum frequency component to 5 GHz that is two orders of magnitude smaller than the level of the DC component of each rectangular pulse.

In Figure 6, the TDR at lumped port 1 is presented in terms of impedance. The computed port impedance is around 50 Ω while the signal level is 1 V.

Notes About the COMSOL Implementation

Changing the number of output times in the **Step 1: Time Dependent** node configures the output times for the results analysis but has a minimal effect on the time steps taken by the solver.

Reference

1. D.M. Pozar, Microwave Engineering, John Wiley & Sons, 1998.

Application Library path: RF_Module/EMI_EMC_Applications/ microstrip_line_crosstalk

Modeling Instructions

From the File menu, choose New.

NEW

In the New window, click 🙆 Model Wizard.

MODEL WIZARD

- I In the Model Wizard window, click 间 3D.
- 2 In the Select Physics tree, select Radio Frequency>Electromagnetic Waves, Transient (termw).
- 3 Click Add.
- 4 Click 🔿 Study.
- 5 In the Select Study tree, select General Studies>Time Dependent.
- 6 Click **M** Done.

GLOBAL DEFINITIONS

Parameters 1

I In the Model Builder window, under Global Definitions click Parameters I.

- 2 In the Settings window for Parameters, locate the Parameters section.
- 3 Click **b** Load from File.
- 4 Browse to the model's Application Libraries folder and double-click the file microstrip_line_crosstalk_parameters.txt.

GEOMETRY I

- I In the Model Builder window, under Component I (compl) click Geometry I.
- 2 In the Settings window for Geometry, locate the Units section.
- 3 From the Length unit list, choose in.

Block I (blkI)

- I In the **Geometry** toolbar, click 🗍 **Block**.
- 2 In the Settings window for Block, locate the Size and Shape section.
- 3 In the Width text field, type blength+0.5.
- 4 In the **Depth** text field, type bwidth.
- 5 In the **Height** text field, type tsub*15.
- 6 Locate the Position section. In the x text field, type -0.25.
- 7 In the y text field, type -bwidth/2.
- 8 Click to expand the Layers section. Find the Layer position subsection. Select the Left check box.
- 9 Select the **Right** check box.
- **IO** Clear the **Bottom** check box.
- II In the table, enter the following settings:

Layer name	Thickness (in)	
Layer 1	0.25	

12 Click the **Wireframe Rendering** button in the **Graphics** toolbar.

Block 2 (blk2)

- I In the **Geometry** toolbar, click 🗍 **Block**.
- 2 In the Settings window for Block, locate the Size and Shape section.
- 3 In the Width text field, type blength.
- 4 In the **Depth** text field, type bwidth.
- 5 In the **Height** text field, type tsub.
- 6 Locate the Position section. In the y text field, type -bwidth/2.

Block 3 (blk3)

- I In the **Geometry** toolbar, click 🗍 Block.
- 2 In the Settings window for Block, locate the Size and Shape section.
- 3 In the Width text field, type blength.
- 4 In the **Depth** text field, type lwidth.
- 5 In the **Height** text field, type tsub.
- 6 Locate the Position section. In the y text field, type spacing/2-lwidth.

Mirror I (mir I)

- I In the Geometry toolbar, click 📿 Transforms and choose Mirror.
- 2 Select the object **blk3** only.
- 3 In the Settings window for Mirror, locate the Input section.
- 4 Select the Keep input objects check box.
- 5 Locate the Normal Vector to Plane of Reflection section. In the y text field, type 1.
- **6** In the **z** text field, type 0.
- 7 Click 📗 Build All Objects.



GLOBAL DEFINITIONS

Rectangle | (rect |)

I In the Home toolbar, click f(X) Functions and choose Global>Rectangle.

- 2 In the Settings window for Rectangle, locate the Parameters section.
- **3** In the **Lower limit** text field, type **0**.
- 4 In the **Upper limit** text field, type Tb-Tb/4.
- 5 Click to expand the Smoothing section. In the Size of transition zone text field, type Tb/4.

Analytic I (an I)

- I In the Home toolbar, click f(X) Functions and choose Global>Analytic.
- 2 In the Settings window for Analytic, locate the Definition section.
- 3 In the Expression text field, type rect1((t-Tb/8)/1[s]).
- 4 In the Arguments text field, type t.
- **5** Locate the **Units** section. In the table, enter the following settings:

Argument	Unit
t	s

6 In the Function text field, type V.

7 Locate the Plot Parameters section. In the table, enter the following settings:

Argument	Lower limit	Upper limit	Unit
t	0	2*Tb	S

8 Click 💽 Plot.



MATERIALS

Material I (mat1)

- I In the Model Builder window, under Component I (compl) right-click Materials and choose Blank Material.
- 2 In the Settings window for Material, locate the Material Contents section.
- **3** In the table, enter the following settings:

Property	Variable	Value	Unit	Property group
Relative permittivity	epsilonr_iso ; epsilonrii = epsilonr_iso, epsilonrij = 0	1	I	Basic
Relative permeability	mur_iso ; murii = mur_iso, murij = 0	1	I	Basic
Electrical conductivity	sigma_iso ; sigmaii = sigma_iso, sigmaij = 0	0	S/m	Basic

Material 2 (mat2)

- I Right-click Materials and choose Blank Material.
- **2** Select Domains 2 and 4–7 only.



- 3 In the Settings window for Material, locate the Material Contents section.
- **4** In the table, enter the following settings:

Property	Variable	Value	Unit	Property group
Relative permittivity	epsilonr_iso ; epsilonrii = epsilonr_iso, epsilonrij = 0	er_sub	I	Basic
Relative permeability	mur_iso ; murii = mur_iso, murij = 0	1	I	Basic
Electrical conductivity	sigma_iso ; sigmaii = sigma_iso, sigmaij = 0	0	S/m	Basic

ELECTROMAGNETIC WAVES, TRANSIENT (TEMW)

Perfect Electric Conductor 2

- I In the Model Builder window, under Component I (compl) right-click Electromagnetic Waves, Transient (temw) and choose Perfect Electric Conductor.
- 2 Select Boundaries 16 and 24 only.



Scattering Boundary Condition I I In the Physics toolbar, click 🕞 Boundaries and choose Scattering Boundary Condition. **2** Select Boundaries 1, 2, 4, 5, 7, 10, 12, 29, 30, 32, 35, 40, and 41 only.



Lumped Port I

- I In the Physics toolbar, click 📄 Boundaries and choose Lumped Port.
- 2 Select Boundary 21 only.

For the first port, wave excitation is **on** by default.

- 3 In the Settings window for Lumped Port, locate the Settings section.
- **4** In the V_0 text field, type an1(t).

Lumped Port 2

- I In the Physics toolbar, click 🔚 Boundaries and choose Lumped Port.
- 2 Select Boundary 38 only.

Lumped Port 3

- I In the Physics toolbar, click 📄 Boundaries and choose Lumped Port.
- 2 Select Boundary 13 only.

Lumped Port 4

- I In the Physics toolbar, click 📄 Boundaries and choose Lumped Port.
- 2 Select Boundary 36 only.

MESH I

I In the Model Builder window, under Component I (compl) click Mesh I.

- 2 In the Settings window for Mesh, locate the Sequence Type section.
- **3** From the list, choose **User-controlled mesh**.

Size

- I In the Model Builder window, under Component I (compl)>Mesh I click Size.
- 2 In the Settings window for Size, locate the Element Size section.
- **3** Click the **Custom** button.
- **4** Locate the **Element Size Parameters** section. In the **Maximum element size** text field, type hm.

Edge I

- I In the Mesh toolbar, click \bigwedge Boundary and choose Edge.
- 2 Select Edges 18, 20, 23, 25, 28, and 30 only.



Distribution I I Right-click Edge I and choose Distribution. 2 Select Edges 18, 20, 28, and 30 only.



- 3 In the Settings window for Distribution, locate the Distribution section.
- 4 From the Distribution type list, choose Predefined.
- **5** In the **Number of elements** text field, type **3**.
- 6 In the Element ratio text field, type 4.
- 7 Select the Symmetric distribution check box.

Distribution 2

I In the Model Builder window, right-click Edge I and choose Distribution.

2 Select Edges 23 and 25 only.



- 3 In the Settings window for Distribution, locate the Distribution section.
- 4 From the Distribution type list, choose Predefined.
- **5** In the **Number of elements** text field, type **4**.
- 6 In the **Element ratio** text field, type 4.
- 7 Select the Symmetric distribution check box.

Mapped I

I In the Mesh toolbar, click \triangle Boundary and choose Mapped.

2 Select Boundaries 13, 17, and 21 only.



Distribution I

- I Right-click Mapped I and choose Distribution.
- **2** Select Edges 17 and 32 only.



3 In the Settings window for Distribution, locate the Distribution section.

4 In the Number of elements text field, type 2.

Free Triangular 1

- I In the Mesh toolbar, click \triangle Boundary and choose Free Triangular.
- 2 Select Boundaries 6, 9, and 25 only.



Swept I

- I In the Mesh toolbar, click 🎄 Swept.
- 2 Click the **Zoom Extents** button in the **Graphics** toolbar.
- 3 In the Settings window for Swept, locate the Domain Selection section.
- 4 From the Geometric entity level list, choose Domain.

5 Select Domains 2–7 only.



Swept 2 In the Mesh toolbar, click As Swept.

Free Tetrahedral I

- I In the Model Builder window, under Component I (compl)>Mesh I right-click Free Tetrahedral I and choose Delete.
- 2 Right-click Mesh I and choose Build All.
- 3 Click the 🔌 Click and Hide button in the Graphics toolbar.
- 4 In the Graphics window toolbar, click ▼ next to 📄 Select Edges, then choose Select Boundaries.
- 5 Select Boundary 12 only.
- 6 Select Boundary 10 only.
- 7 Select Boundary 4 only.
- 8 Select Boundary 1 only.
- **9** Select Boundary 2 only.
- **10** Click the 🔌 Click and Hide button in the Graphics toolbar.

Free Triangular I Click the (+) **Zoom to Selection** button in the **Graphics** toolbar.



STUDY I

Step 1: Time Dependent

- I In the Model Builder window, under Study I click Step I: Time Dependent.
- 2 In the Settings window for Time Dependent, locate the Study Settings section.
- 3 In the **Output times** text field, type range(0, sim_time_step, sim_time_max).

Solution 1 (soll)

- I In the Study toolbar, click **The Show Default Solver**.
- 2 In the Model Builder window, expand the Solution I (soll) node, then click Time-Dependent Solver I.
- **3** In the **Settings** window for **Time-Dependent Solver**, click to expand the **Time Stepping** section.
- 4 From the Steps taken by solver list, choose Manual.
- 5 In the Time step text field, type sim_time_step.
- 6 In the Model Builder window, expand the Study I>Solver Configurations>
 Solution I (soll)>Time-Dependent Solver I node, then click Direct.

- 7 In the Settings window for Direct, locate the General section.
- 8 From the Solver list, choose PARDISO.

Parametric Sweep

- I In the Study toolbar, click **Parametric Sweep**.
- 2 In the Settings window for Parametric Sweep, locate the Study Settings section.
- 3 Click + Add.
- **4** In the table, enter the following settings:

Parameter name	Parameter value list	Parameter unit
f0 (Frequency)	300[MHz] 600[MHz]	Hz

5 In the **Study** toolbar, click **= Compute**.

RESULTS

3D Plot Group 1

- I In the Settings window for 3D Plot Group, locate the Data section.
- 2 From the Time (s) list, choose 6E-10.

Multislice I

- I In the Model Builder window, expand the 3D Plot Group I node, then click Multislice I.
- 2 In the Settings window for Multislice, locate the Multiplane Data section.
- 3 Find the X-planes subsection. In the Planes text field, type 0.
- 4 Find the Y-planes subsection. In the Planes text field, type 0.
- 5 Find the Z-planes subsection. From the Entry method list, choose Coordinates.
- 6 In the Coordinates text field, type 0.

7 In the 3D Plot Group I toolbar, click 💿 Plot.

f0(2)=6E8 Hz Time=6E-10 s

Multislice: Electric field norm (V/m)



ID Plot Group 2

- I In the Home toolbar, click 🚛 Add Plot Group and choose ID Plot Group.
- 2 In the Settings window for ID Plot Group, locate the Data section.
- 3 From the Dataset list, choose Study I/Parametric Solutions I (sol2).
- 4 Click to expand the Title section. From the Title type list, choose Manual.
- 5 In the Title text area, type Time domain response at the input port.

Global I

- I Right-click ID Plot Group 2 and choose Global.
- 2 In the Settings window for Global, locate the y-Axis Data section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
temw.Vport_1	V	Lumped port 1 voltage
an1(t)		Input pulse

4 Click to expand the **Coloring and Style** section. Find the **Line markers** subsection. From the **Marker** list, choose **Cycle**.

- 5 From the **Positioning** list, choose **Interpolated**.
- 6 In the ID Plot Group 2 toolbar, click 💿 Plot.

Figure 2 shows the input pulse and the voltage at lumped port 1.

ID Plot Group 3

- I In the Model Builder window, under Results right-click ID Plot Group 2 and choose Duplicate.
- 2 In the Settings window for ID Plot Group, locate the Title section.
- 3 In the Title text area, type Time domain response at the through port.
- 4 Locate the Legend section. From the Position list, choose Middle left.

Global I

- I In the Model Builder window, expand the ID Plot Group 3 node, then click Global I.
- 2 In the Settings window for Global, locate the y-Axis Data section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
temw.Vport_2	V	Lumped port 2 voltage
an1(t-delay)	V	Delayed input pulse

4 In the ID Plot Group 3 toolbar, click 💽 Plot.

Figure 3 shows the delayed input pulse and the voltage at lumped port 2.

ID Plot Group 4

- I In the Home toolbar, click 🚛 Add Plot Group and choose ID Plot Group.
- 2 In the Settings window for ID Plot Group, locate the Data section.
- 3 From the Dataset list, choose Study I/Parametric Solutions I (sol2).
- **4** Locate the **Title** section. From the **Title type** list, choose **Manual**.
- 5 In the Title text area, type Time domain response at the coupled ports.
- 6 Locate the Legend section. From the Position list, choose Upper left.

Global I

- I Right-click ID Plot Group 4 and choose Global.
- 2 In the Settings window for Global, locate the y-Axis Data section.

3 In the table, enter the following settings:

Expression	Unit	Description
temw.Vport_3	V	Lumped port 3 voltage
temw.Vport_4	V	Lumped port 4 voltage

- 4 Locate the Coloring and Style section. Find the Line markers subsection. From the Marker list, choose Cycle.
- **5** From the **Positioning** list, choose **Interpolated**.
- 6 In the ID Plot Group 4 toolbar, click 🗿 Plot.

The coupled signals at lumped port are shown in Figure 4.

ID Plot Group 5

- I In the Home toolbar, click 🚛 Add Plot Group and choose ID Plot Group.
- 2 In the Settings window for ID Plot Group, locate the Data section.
- 3 From the Dataset list, choose Study I/Parametric Solutions I (sol2).
- **4** Locate the **Title** section. From the **Title type** list, choose **Manual**.
- 5 In the Title text area, type Frequency domain response of the input pulse.

Global I

- I Right-click ID Plot Group 5 and choose Global.
- 2 In the Settings window for Global, locate the y-Axis Data section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
an1(t)	V	Input pulse spectrum

- 4 Locate the x-Axis Data section. From the Parameter list, choose Discrete Fourier transform.
- 5 From the Show list, choose Frequency spectrum.
- 6 Select the Frequency range check box.
- 7 In the Maximum text field, type 10[GHz].
- 8 Locate the Coloring and Style section. Find the Line markers subsection. From the Marker list, choose Cycle.
- 9 From the Positioning list, choose Interpolated.

IO In the **ID Plot Group 5** toolbar, click **ID Plot**.



II Click the **y-Axis Log Scale** button in the **Graphics** toolbar.

Compare to the spectra of input pulses in Figure 5.

ID Plot Group 6

- I In the Home toolbar, click 🚛 Add Plot Group and choose ID Plot Group.
- 2 In the Settings window for ID Plot Group, locate the Data section.
- 3 From the Dataset list, choose Study I/Parametric Solutions I (sol2).

Global I

- I Right-click ID Plot Group 6 and choose Global.
- 2 In the Settings window for Global, click Add Expression in the upper-right corner of the y-Axis Data section. From the menu, choose Component I (comp1)>
 Electromagnetic Waves, Transient>Ports>temw.Zport_I Lumped port impedance Ω.
- **3** Locate the **Coloring and Style** section. Find the **Line markers** subsection. From the **Marker** list, choose **Cycle**.
- **4** From the **Positioning** list, choose **Interpolated**.
- 5 In the ID Plot Group 6 toolbar, click 💽 Plot.

Figure 6 describes the impedance of lumped port 1 with two data rates as a function of time.

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